

# **GRF5020**

30.5 dBm Power-LNA™ Tuning Range: 0.1 – 6.0 GHz



#### **Features**

Reference: 8.0V/95mA/2.5GHz

Gain: 18.0 dBNF: 0.85 dB

OP1dB: 29.0 dBmOIP3: 43.0 dBm

Reference: 5.0V/65mA/2.5GHz

Gain: 17.3 dBNF: 0.80 dB

OP1dB: 24.5 dBmOIP3: 37.2 dBm

Flexible Bias Voltage and Current

Process: GaAs pHEMT

#### **Applications**

Multi-stage LNA

 Linear Driver Amplifier for High PAR Waveforms

Distributed Antenna Systems

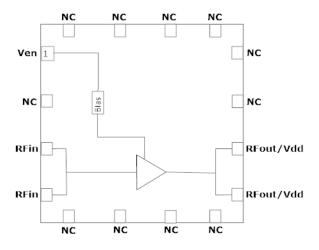
Microwave Backhaul

#### **Product Description**

GRF5020 is a high linearity PA with ultra-low noise figure (NF). The primary tune for this device covers 1.7 to 2.7 GHz and it achieves outstanding P1dB, IP3 and NF over the band. The device can be tuned to deliver outstanding performance over 0.1 GHz. to 6.0 GHz with fractional bandwidths >30%. With a 10.0 Volt supply, the device can deliver broadband OP1dB values >30.0 dBm.

In addition to use as a PA or linear driver, GRF5020 is well suited to demanding first, second or third stage LNA applications requiring high linearity, ruggedness and low NF.

Consult with the GRF applications engineering team for custom tuning/evaluation board data and device sparameters.



3.0 x 3.0 mm QFN-16



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### **Absolute Ratings:**

Parameter	Symbol	Min.	Max.	Unit
Drain Voltage	V <sub>DD</sub>		12.0	V
Transient Average RF Input Power CW: (Load VSWR < 2:1; Duration: <1 hour)	PIN MAX		22.0	dBm
Average RF Output Power: (Load VSWR < 2:1; V <sub>D</sub> : > 8.0 volts; Duration: Continuous)	P <sub>OUT MAX</sub>		26.0	dBm
Average RF Output Power: (Load VSWR < 2:1; V <sub>D</sub> : <= 8.0 volts; Duration: Continuous)	Роит мах		NA	dBm
Operating Temperature (Package Heat Sink)	T <sub>AMB</sub>	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P <sub>DISS MAX</sub>		1.9	W
Electrostatic Discharge:				
Charged Device Model: (TBD)	CDM	1500		V
Human Body Model:	НВМ	250		V
Storage:				
Storage Temperature	T <sub>STG</sub>	-65	150	°C
Moisture Sensitivity Level	MSL		1	-



Caution! ESD Sensitive Device



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Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For package dimensions and manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF5020 landing page: Manufacturing Note-MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

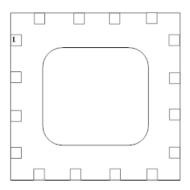
Link to manufacturing note



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### Pin Out (Top View)



### Pin Assignments:

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Pin	Name	Description	Note
1	VENABLE	Enable Voltage Input	Venable and series resistor set IDDQ. Venable < =0.2 volts disables device. On-die pull-down resistor will turn the part off if this node is allowed to float.
2	NC	No Connect or Ground	No internal connection to die
3	RF_In	RF Input	Pins 3-4 tied together on system board
4	RF_In	RF Input	Pins 3-4 tied together on system board
5	NC	No Connect or Ground	No internal connection to die
6	NC	No Connect or Ground	No internal connection to die
7	NC	No Connect or Ground	No internal connection to die
8	NC	No Connect or Ground	No internal connection to die
9	RF_Out/VDD	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.
10	RF_Out/VDD	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.
11	NC	No Connect or Ground	No internal connection to die
12	NC	No Connect or Ground	No internal connection to die
13	NC	No Connect or Ground	No internal connection to die
14	NC	No Connect or Ground	No internal connection to die
15	NC	No Connect or Ground	No internal connection to die
16	NC	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



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### **Nominal Operating Parameters:**

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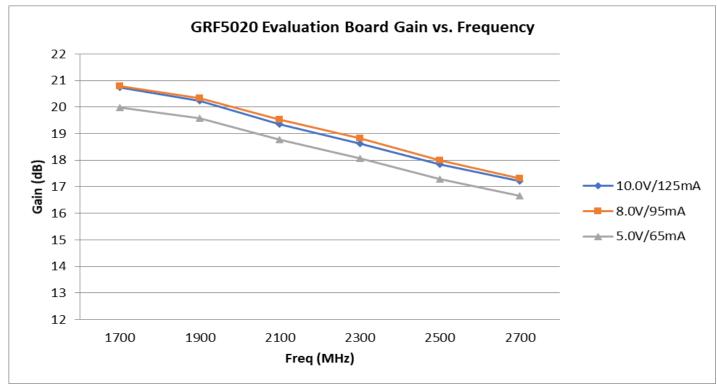
Parameter	Cymahal	Specification			Heit	Condition	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Target Performance (1.7-3.8 GHz Tune)						Bias: 8.0 V and 95 mA unless otherwise noted. (+25C)	
Test Frequency	FTEST		2.5		GHz		
Gain	S(2,1)	16.0	17.5		dB		
Noise Figure (Evaluation Board)	NF		0.85	1.05	dB		
Output 1dB Compression Point	OP1dB	27.5	29.0		dBm		
Output Third Order Intercept Point	OIP3		43.0		dBm	Tones: 2499 and 2501 MHz at 8.0 dBm per tone	
Switching Rise Time	Trise		200		ns		
Switching Fall Time	TFALL		200		ns		
Quiescent Supply Current	IDDQ		95		mA		
Enable Current	IENABLE		2.0		mA		
Disabled Mode						VDD: 8.0 volts; VENABLE: 0.0 volts	
Supply Current (Leakage)	I <sub>DD</sub>		300	600	uA		
Thermal Data							
Thermal Resistance: (IR Scan Method)	Θјс		43		°C/W		
Channel Temperature @ +85C Reference (package heat sink)	TCHANNEL		118		°C	VDD: 8.0 volts; IDDQ: 95 mA	
						Poiss: 0.76 W; No RF	

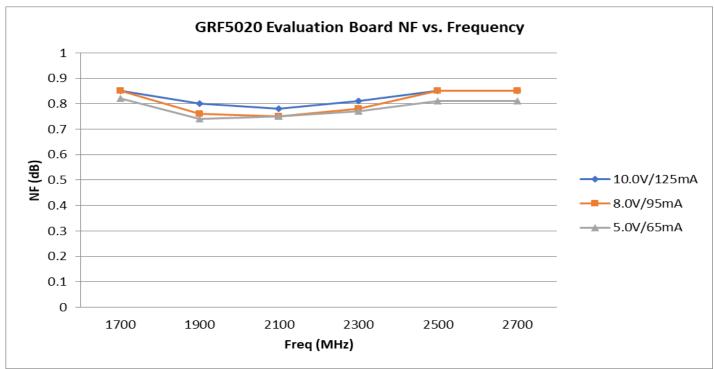


## **GRF5020**

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### **GRF5020 Evaluation Board Data vs. Supply Voltage (1.7 to 2.7GHz Tune)**



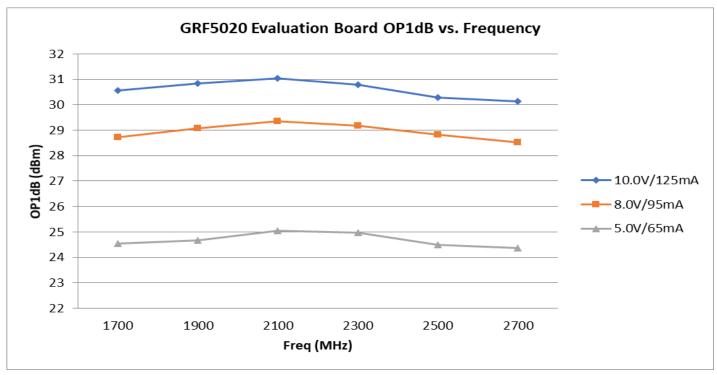


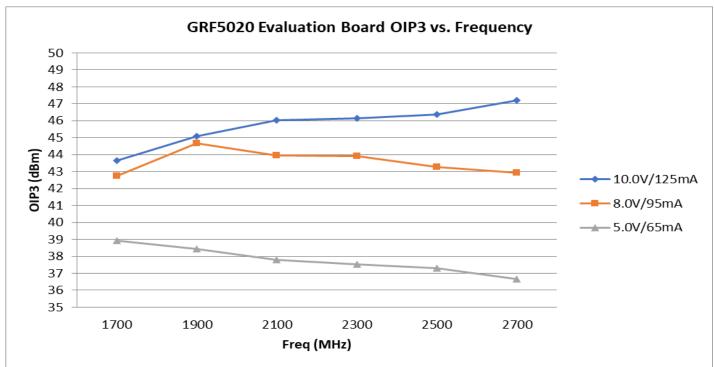


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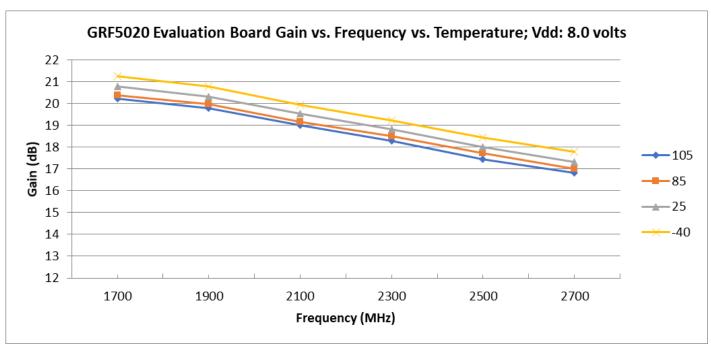


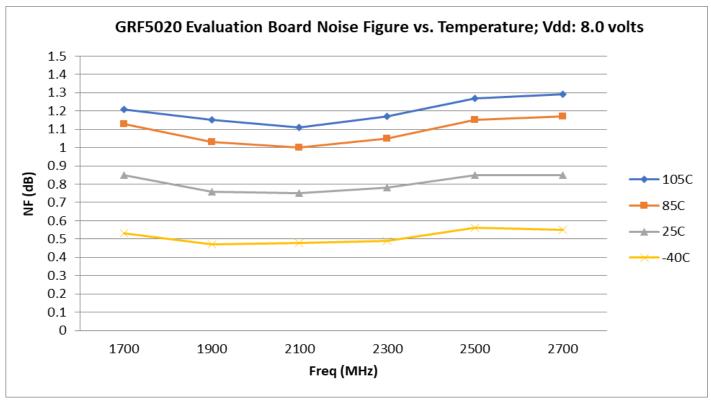


## **GRF5020**

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**GRF5020** Evaluation Board Data vs. Temperature; Bias: 8.0 volts (1.7 to 2.7GHz Tune)







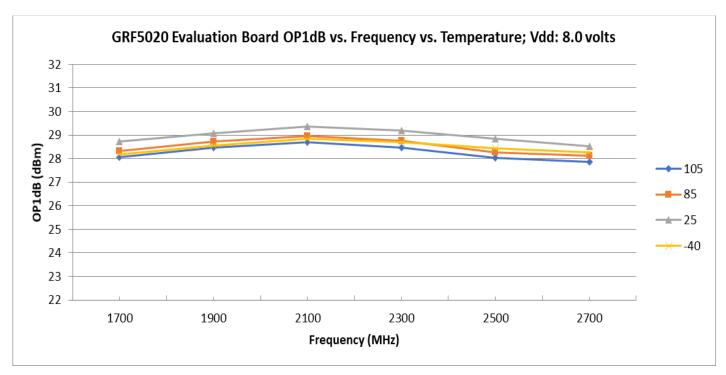
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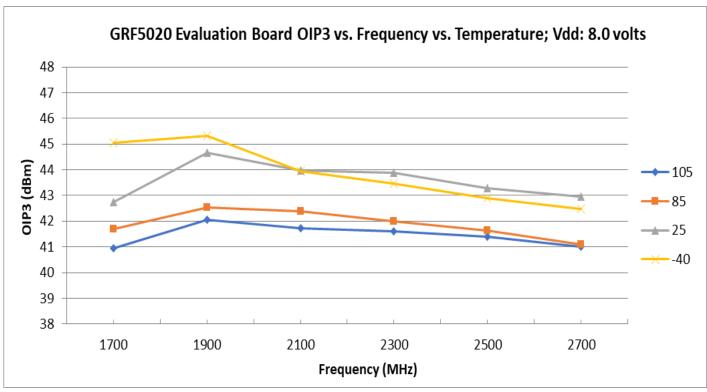
### Released

# **GRF5020**

30.5 dBm Power-LNA™ Tuning Range: 0.1 – 6.0 GHz

#### GRF5020 Evaluation Board Data vs. Temperature; Bias: 8.0 volts (1.7 to 2.7GHz Tune)



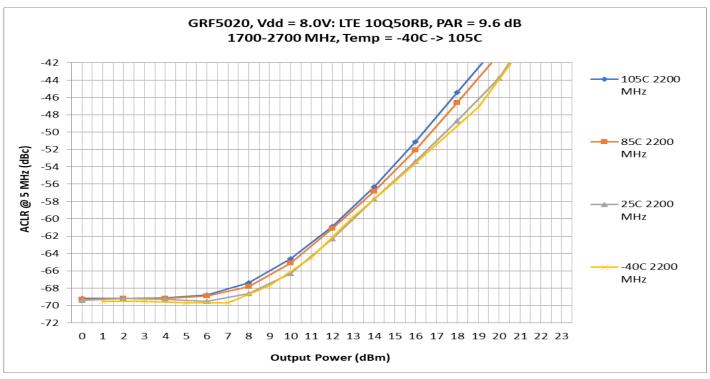


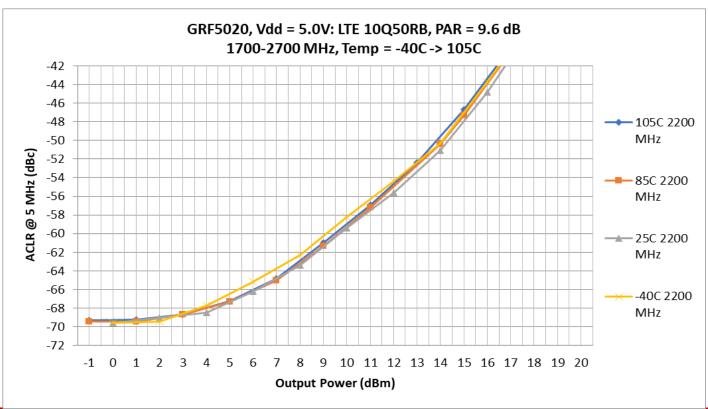


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#### **GRF5020 Evaluation Board Data vs. Temperature**; (1.7 to 2.7GHz Tune)





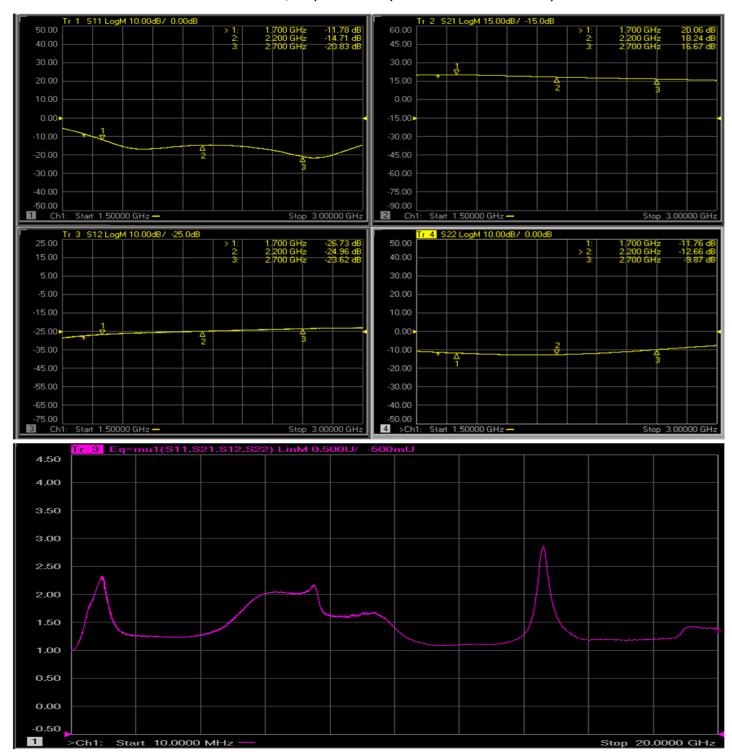
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### GRF5020 Evaluation Board S-Pars; 5V/95 mA: (1.7 to 2.7 GHz Tune)

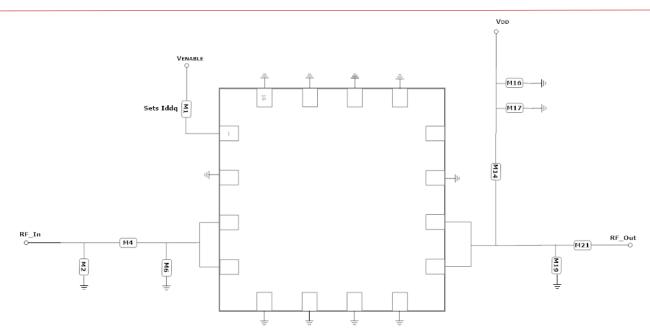


Note: Mu factor >= 1.0 implies unconditional stability.

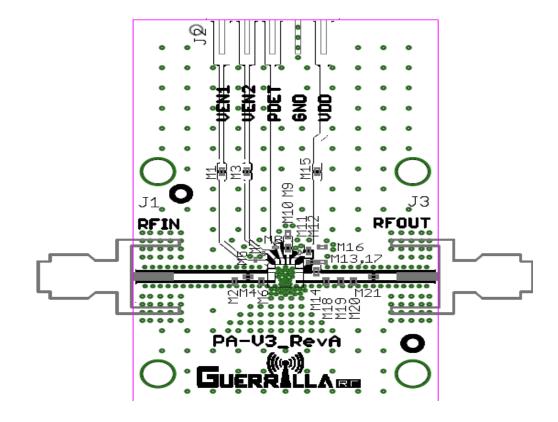


# **GRF5020**

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**GRF5020 Application Schematic:** (1.7 to 2.7 GHz)



**GRF50XX Evaluation Board Assembly Drawing** 



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### GRF5020 Evaluation Board BOM: (1.7—2.7GHz)

Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M1 (See curves)	Resistor	Various	5%	Sets Iddq	0402	ok
M2	Inductor: High Q	Coilcraft	НР	3.3 nH	0402	ok
M4	Capacitor: High Q	Murata	GJM	2.0 pF	0402	ok
M6	Capacitor: High Q	Murata	GJM	1.8 pF	0402	ok
M13	Capacitor	Murata	GRM	100 pF	0402	ok
M14	Inductor: High Q	Coilcraft	НР	15 nH	0402	ok
M16	Capacitor	Murata	GRM	0.1 uF	0402	ok
M19	DNP	_	_	_	_	_
M21	Capacitor	Murata	GJM	18 pF	0402	ok
Evaluation Board	PA-V3_RevA					

Note: Standard evaluation board bias: Vdd: 8.0V; Venable: 5.0V; M1:



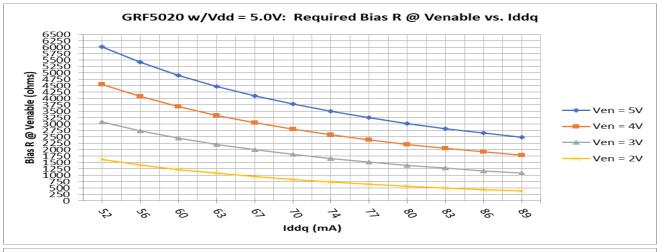
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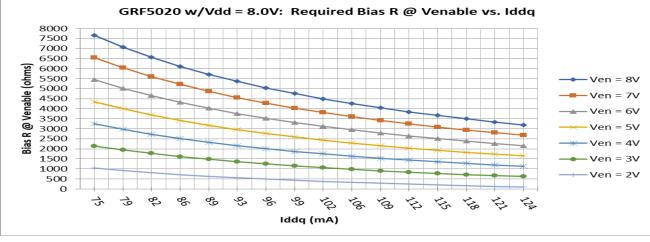
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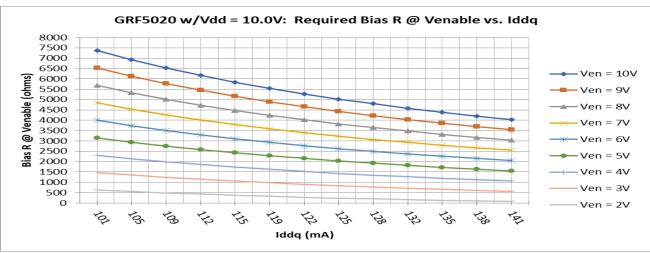
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#### **GRF5020 Bias Resistor (M1) Selection Curves:**







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# **GRF5020**

### 30.5 dBm Power-LNA™ Tuning Range: 0.1 – 6.0 GHz

Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

Revision Date: 02/26/18

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